

# **Excellent Integrated System Limited**

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VFT3060G-M3/4W</u>

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### Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VFT3060G-M3/4W - DIODE SCHOTTKY 30A 60V ITO-220AB

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# **VFT3060G**

COMPLIANT

**FREE** 

Vishay General Semiconductor

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.40 \text{ V}$  at  $I_F = 5 \text{ A}$ 



VF13060G					
PIN 1 O	PIN 2				
PIN 3 O					

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
$V_{RRM}$	60 V			
I <sub>FSM</sub>	150 A			
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.61 V			
T <sub>J</sub> max.	150 °C			
Package	ITO-220AB			
Diode variation	Dual common cathode			

### **FEATURES**

- · Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT3060G	UNIT
Maximum repetitive peak reverse voltage		$V_{RRM}$	60	V
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	30	A
	per diode		15	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	150	А
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs
Isolation voltage from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500	V
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> (1)	0.49	-	. V
	I <sub>F</sub> = 7.5 A			0.53	-	
	I <sub>F</sub> = 15 A			0.65	0.73	
	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 125 °C		0.40	-	
	I <sub>F</sub> = 7.5 A			0.46	-	
	I <sub>F</sub> = 15 A			0.61	0.69	
Reverse current per diode	V <sub>R</sub> = 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	850	μA
	v <sub>R</sub> = 60 V	T <sub>A</sub> = 125 °C		14	40	mA

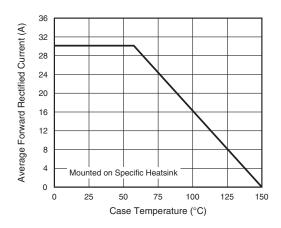
#### Notes

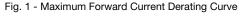
<sup>(2)</sup> Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT3060G	UNIT
Typical thermal resistance	per diode	$R_{ heta JC}$	6.2	°C/W
	per device		5.0	C/VV

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	VFT3060G-M3/4W	1.76	4W	50/tube	Tube	

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





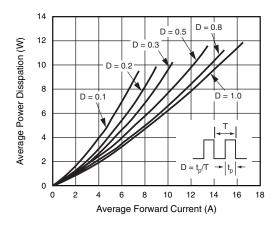


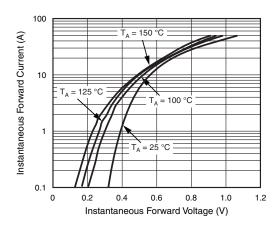
Fig. 2 - Forward Power Dissipation Characteristics

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

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Fig. 3 - Typical Instantaneous Forward Characteristics

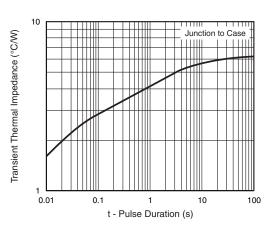


Fig. 5 - Typical Transient Thermal Impedance

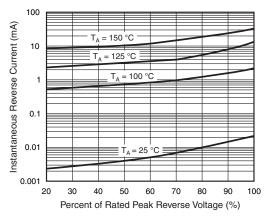


Fig. 4 - Typical Reverse Characteristics

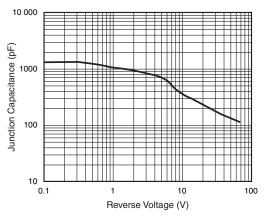
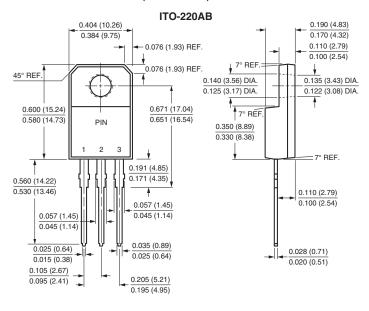


Fig. 6 - Typical Junction Capacitance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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